UNITED STATES

Additional inventure are being named on separately numbered cheets attached hereto.

Docket No.: 1514 1032

COMBINED DECLARATION/POWER OF ATTORNEY FOR UTILITY/DESIGN PATENT APPLICATION N

As a below named inventor, I hereby declare that: My rasidence, post office address and cilizenship are as stated below next to my name. I believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: METHOD FOR MANUFACTURING POLYCRYSTALLING SILICON THIN FILM AND THIN FILM M TRANSISTOR FABRICATED USING POLYCRYSTALLINE SILICON THIN FILM MANUFACTURED BY THE MANUFACTURING METHOD the specification of which is attached hereto, unless the following hox is checked: was filed on __ as United States Application Number or PCT International Application Number __TO BE ASSIGNED_ and was amended on (if applicable). I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amenoment reteried to above.

I acknowledge the duty to disclose information which is material to potentability as defined in 37 C.F.R. § 1.56.

I hereby claim foreign priority benefit(s) under 35 U.S.C. · 119(a)-(d) or · 305(a)-(e) of any foreign application(s) for patent or inventor's certificate having a filing data before that of the listed below and have also identified heliow any foreign application(s) for patent or inventor's certificate having a filing data before that of the application on which priority is claimed. Priority NOT Prior Foreign Application(s) Claimed 26/February/2003 Republic of Korea 2003-12101 Day/Month/Year Filed (Country) (Number) 11 Day/Month/Year Filed (Country) (Number) Thereby claim the benefit under 35 U.S.O. 120 or 119(c) of any United States application(s), or 1365(c) of any PCT international application designating the United States, listed below and, insofar as the subject maller of each of the claims of this application is not disclosed in the prior designating the United States, listed below and, insofar as the subject maller of each of the claims of this application is not disclosed in the prior United States or PCT International application(s) in the manner provided by the first paragraph of 35 U.S.C. 112, I acknowledge the duty to disclose information which is material to patentability as defined in 37 C.F.R. 1.56 which became available between the filing date of the prior consideration of the prior c application and the national or PCT luternational filing data of this application. (Status - patented, pending, abandoned) (Filing Date) (Application Serial No.) (Status - patented, pending, abandoned) (Filing Date) (Application Serial No.) I hereby appoint the attorneys and agents of Staas & Haisey (LP under USPTO Customer No. 21,171 to presecute this application and to transact all business in the Patent and Trademark Office connected therewith: I hereby declare that all statements made herein of my own knowledge are true and that all statements made un information and belief ere believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are purishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may peopardize the validity of the application or any patent issued thereon. Full name of sole or first inventor PARK, JI Yung 2003 October 21, **Date** Inventor's Signature Citizenship Republic of Kores Residence Suwon-city, Korea Mailing Address 393-5. Youngtong-dong, Paldal-qu, Suwon city, Gyeonggi-do, Korga PARK, HVe HVang Full name of second inventor October 21, 2003 Date Inventor's Signature Citizenship Republic of Kurea Residence Suwan-city Kores Mailing Address 1285-7, Gwonseon-donu, Gwonseon-gu, Suwon-clty, Cyeonggi-do, Koroa